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[VS-112CNQ030APBF](#)

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## VS-112CNQ030APbF Series

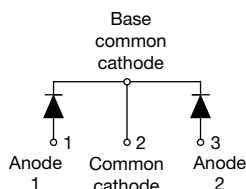
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### High Performance Schottky Rectifier New Generation 3, D-61 Package, 2 x 55 A

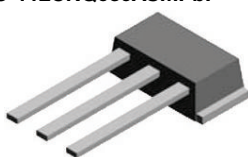
VS-112CNQ030APbF



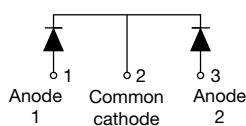
D-61-8



VS-112CNQ030ASMPbF



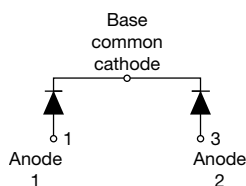
D-61-8-SM



VS-112CNQ030ASLPbF



D-61-8-SL



#### FEATURES

- 150 °C T<sub>J</sub> operation
- Center tap module
- Very low forward voltage drop
- High frequency operation
- High power discrete
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- New fully transfer-mold low profile, small footprint, high current package
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



Available  
RoHS\*  
Available

#### Note

\* This datasheet provides information about parts that are RoHS-compliant and/or parts that are non-RoHS-compliant. For example, parts with lead (Pb) terminations are not RoHS-compliant. Please see the information/tables in this datasheet for details.

#### DESCRIPTION

The center tap Schottky rectifier module has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

PRODUCT SUMMARY	
Package	D-61-8, D-61-8-SM, D-61-8-SL
I <sub>F(AV)</sub>	2 x 55 A
V <sub>R</sub>	30 V
V <sub>F</sub> at I <sub>F</sub>	0.49 V
I <sub>RM</sub> max.	400 mA at 125 °C
T <sub>J</sub> max.	150 °C
Diode variation	Common cathode
E <sub>AS</sub>	36 mJ

MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL	CHARACTERISTICS	VALUES	UNITS
I <sub>F(AV)</sub>	Rectangular waveform	110	A
V <sub>R</sub>		30	V
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	5100	A
V <sub>F</sub>	55 A <sub>pk</sub> , T <sub>J</sub> = 125 °C (per leg)	0.39	V
T <sub>J</sub>	Range	-55 to +150	°C

VOLTAGE RATINGS			
PARAMETER	SYMBOL	VS-112CNQ030APbF	UNITS
Maximum DC reverse voltage	V <sub>R</sub>	30	V
Maximum working peak reverse voltage	V <sub>RWM</sub>		



## VS-112CNQ030APbF Series

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ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current See fig. 5	$I_{F(AV)}$	per leg	50 % duty cycle at $T_C = 131\text{ }^\circ\text{C}$ , rectangular waveform	55	A
		per device		110	
Maximum peak one cycle non-repetitive surge current per leg See fig. 7	$I_{FSM}$	5 $\mu\text{s}$ sine or 3 $\mu\text{s}$ rect. pulse	Following any rated load condition and with rated $V_{RRM}$	5100	A
		10 ms sine or 6 ms rect. pulse		880	
Non-repetitive avalanche energy per leg	$E_{AS}$	$T_J = 25\text{ }^\circ\text{C}$ , $I_{AS} = 8\text{ A}$ , $L = 1.12\text{ mH}$		36	mJ
Repetitive avalanche current per leg	$I_{AR}$	Current decaying linearly to zero in 1 $\mu\text{s}$ Frequency limited by $T_J$ maximum $V_A = 1.5 \times V_R$ typical		8	A

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop per leg See fig. 1	$V_{FM}^{(1)}$	55 A	$T_J = 25\text{ }^\circ\text{C}$	0.49	V
		110 A		0.57	
		55 A	$T_J = 125\text{ }^\circ\text{C}$	0.39	
		110 A		0.51	
Maximum reverse leakage current per leg See fig. 2	$I_{RM}^{(1)}$	$T_J = 25\text{ }^\circ\text{C}$	$V_R = \text{Rated } V_R$	3.5	mA
		$T_J = 125\text{ }^\circ\text{C}$		400	
Maximum junction capacitance per leg	$C_T$	$V_R = 5\text{ }V_{DC}$ , (test signal range 100 kHz to 1 MHz), $25\text{ }^\circ\text{C}$		5100	pF
Typical series inductance per leg	$L_S$	Measured lead to lead 5 mm from package body		5.5	nH
Maximum voltage rate of change	dV/dt	Rated $V_R$		10 000	V/ $\mu\text{s}$

**Note**

 (1) Pulse width < 300  $\mu\text{s}$ , duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum junction and storage temperature range	$T_J, T_{Stg}$			-55 to +150	$^\circ\text{C}$
Maximum thermal resistance, junction to case per leg	$R_{thJC}$	DC operation See fig. 4		0.5	$^\circ\text{C/W}$
Maximum thermal resistance, junction to case per package		DC operation		0.25	
Typical thermal resistance, case to heatsink (D-61-8 only)	$R_{thCS}$	Mounting surface, smooth and greased Device flatness < 5 mils		0.30	
Approximate weight				7.8	g
				0.28	oz.
Mounting torque (D-61-8 only)	minimum			40 (35)	kgf · cm (lbf · in)
	maximum			58 (50)	
Marking device		Case style D-61-8		112CNQ030A	
		Case style D-61-8-SM		112CNQ030ASM	
		Case style D-61-8-SL		112CNQ030ASL	



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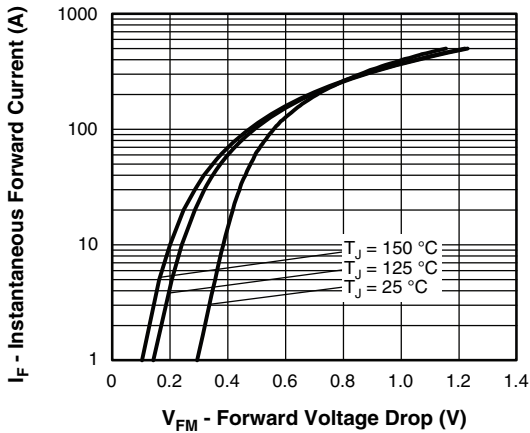


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

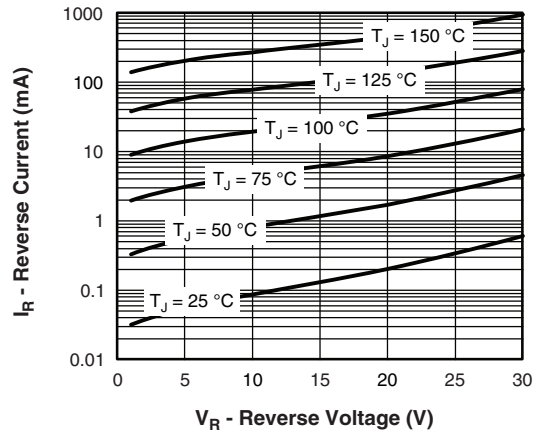


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

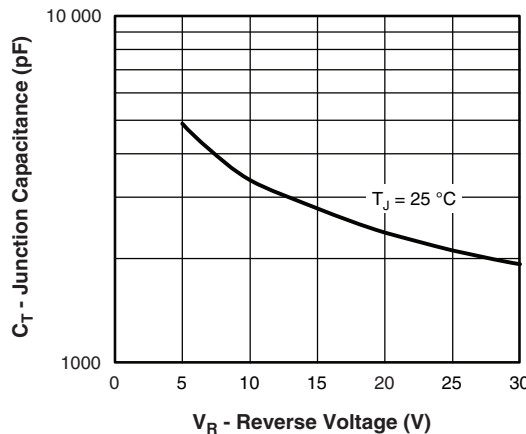


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

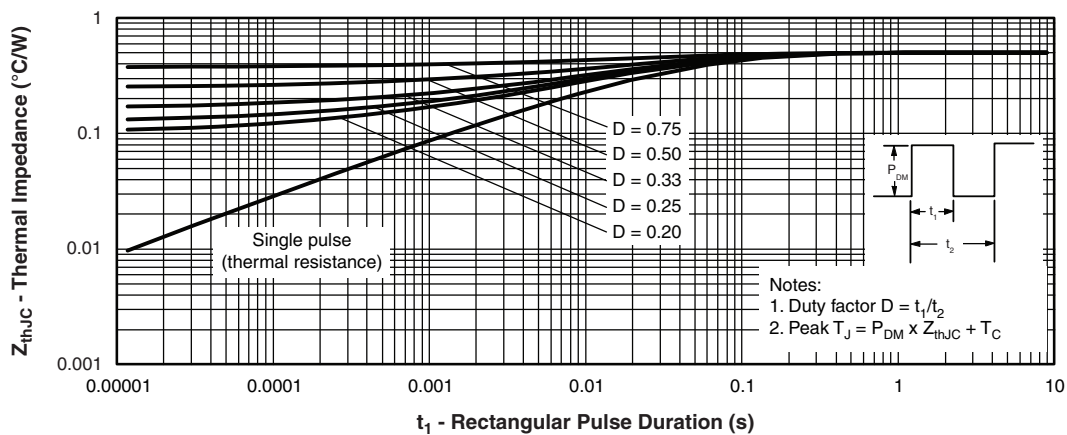


Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics (Per Leg)



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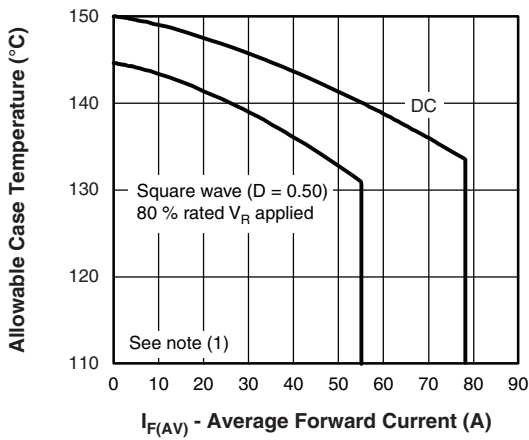


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

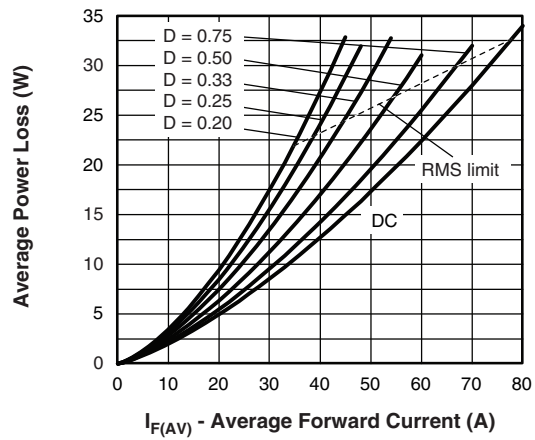


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

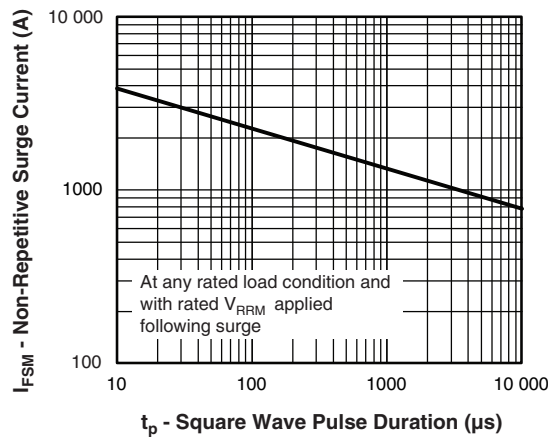


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

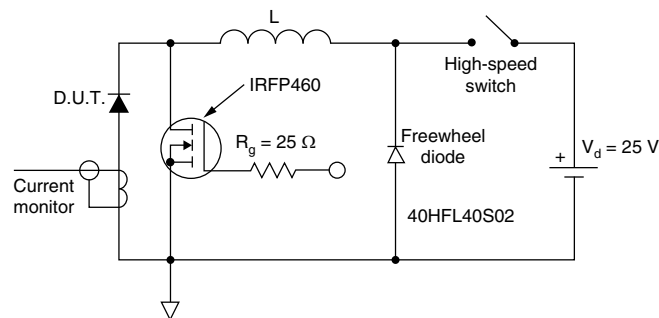


Fig. 8 - Unclamped Inductive Test Circuit

**Note**

- (1) Formula used:  $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$ ;
- $P_d$  = Forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6);
- $P_{d_{REV}}$  = Inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1} = 80\%$  rated  $V_R$



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## VS-112CNQ030APbF Series

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### ORDERING INFORMATION TABLE

Device code	<b>VS-</b>	<b>112</b>	<b>C</b>	<b>N</b>	<b>Q</b>	<b>030</b>	<b>A</b>	<b>PbF</b>
	①	②	③	④	⑤	⑥	⑦	⑧

- 1** - Vishay Semiconductors product
- 2** - Current rating (110 A)
- 3** - Circuit configuration:  
C = common cathode
- 4** - Package:  
N = D-61
- 5** - Schottky "Q" series
- 6** - Voltage rating (030 = 30 V)
- 7** - Package style:
  - A = D-61-8
  - ASM = D-61-8-SM
  - ASL = D-61-8-SL
- 8** -
  - None = standard production
  - PbF = lead (Pb)-free

Standard pack quantity: A = 10 pieces; ASM/ASL = 20 pieces

LINKS TO RELATED DOCUMENTS	
Dimensions	<a href="http://www.vishay.com/doc?95354">www.vishay.com/doc?95354</a>
Part marking information	<a href="http://www.vishay.com/doc?95356">www.vishay.com/doc?95356</a>



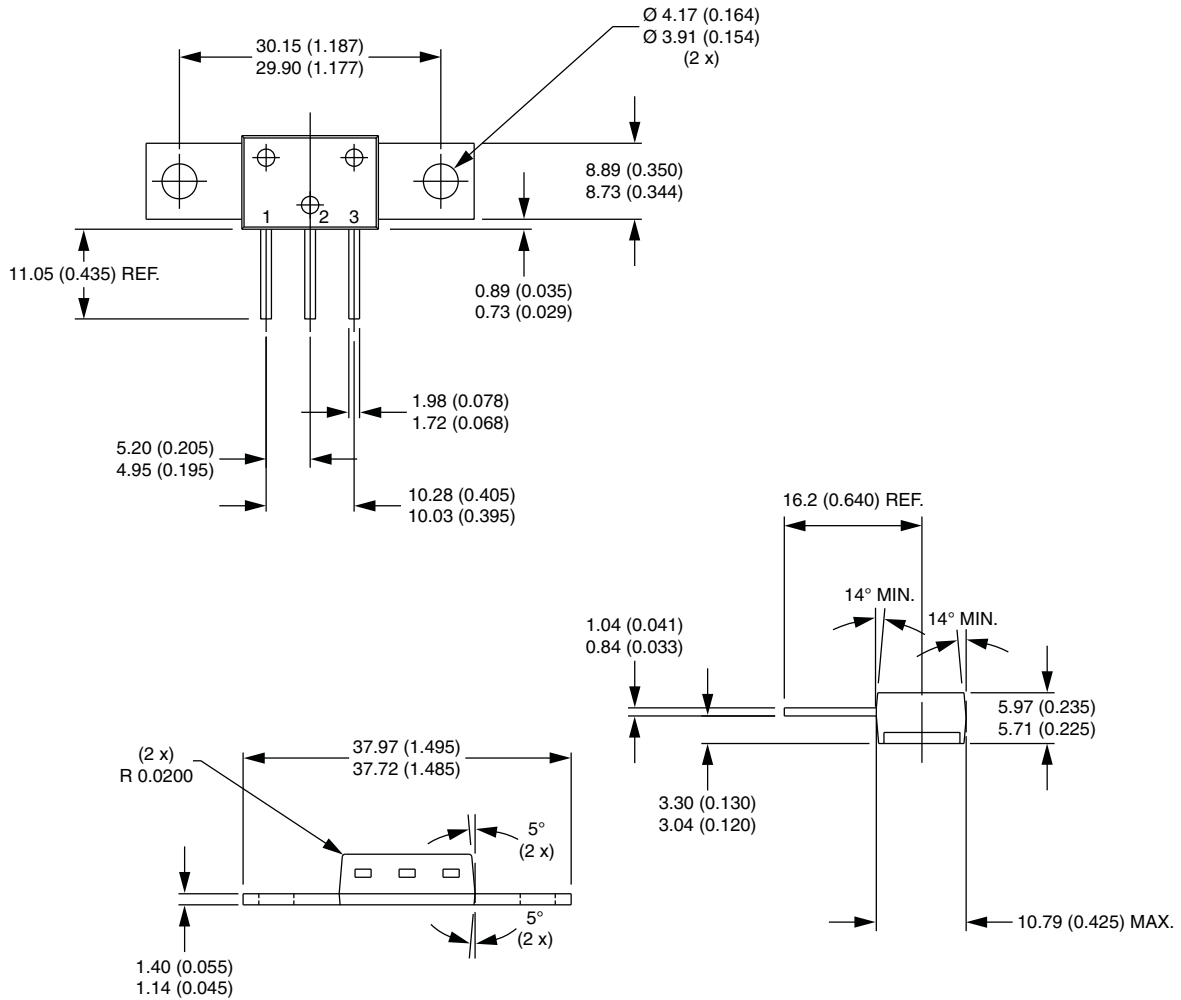
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## Outline Dimensions

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### D-61-8, D-61-8-SM, D-61-8-SL

**DIMENSIONS - D-61-8** in millimeters (inches)



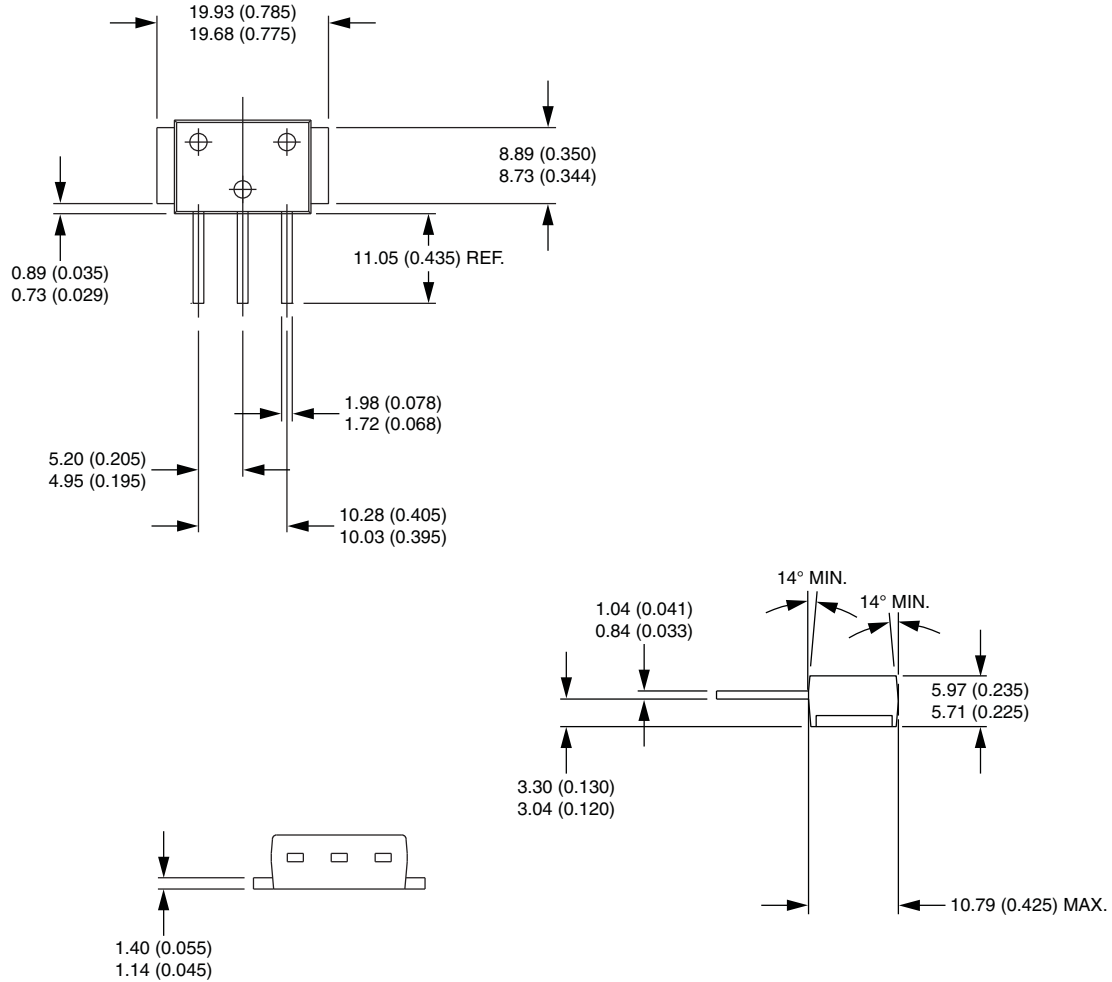


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## Outline Dimensions

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### DIMENSIONS - D-61-8-SM in millimeters (inches)





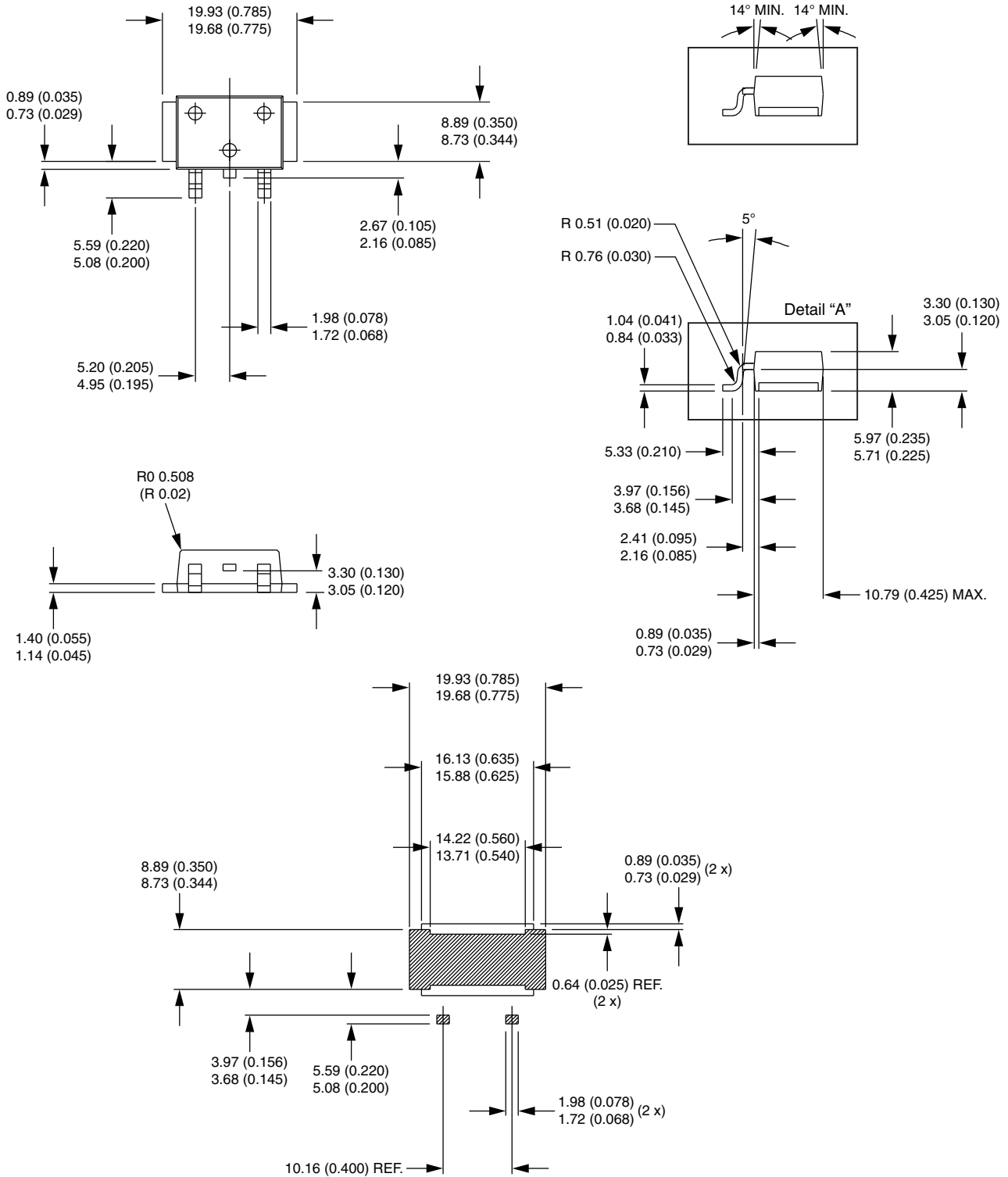


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## Outline Dimensions

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### DIMENSIONS - D-61-8-SL in millimeters (inches)





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